

BGU6009/N2

Low-noise amplifier MMIC for GPS, GLONASS, Galileo and COMPASS

Rev. 4 — 18 January 2017

Product data sheet

1. Product profile

1.1 General description

The BGU6009/N2 is, also known as the GPS1002M, a Low-Noise Amplifier (LNA) for GNSS receiver applications in a plastic leadless 6-pin, very thin small outline SOT1230 package. The BGU6009/N2 requires only one external matching inductor and one external decoupling capacitor.

1.2 Features and benefits

- Covers full GNSS L1 band, from 1559 MHz to 1610 MHz
- Noise figure = 0.9 dB
- Gain 17 dB
- High input 1 dB compression point P_{i(1dB)} of -4 dBm
- High out of band IP3_i of 7 dBm
- Supply voltage 1.5 V to 3.1 V
- Power-down mode current consumption < 2 μA
- Optimized performance at low supply current of 5.1 mA
- Integrated matching for the output
- Requires only one input matching inductor and one supply decoupling capacitor
- Input and output DC decoupled
- ESD protection on all pins (HBM > 2 kV)
- Integrated temperature stabilized bias for easy design
- Small 6-pin leadless package 1.1 mm × 0.9 mm × 0.47 mm; 0.4 mm pitch: SOT1230

1.3 Applications

LNA for GPS, GLONASS, Gallileo and COMPASS (Beidou).

- Smart phones and feature phones
- Tablet PCs
- Personal Navigation Devices
- Digital Still Cameras
- Digital Video Cameras
- RF front-end modules
- Complete GPS chip set modules and theft protection (laptop, ATM)



1.4 Quick reference data

Table 1. Quick reference data

f = 1559 MHz to 1610 MHz; V_{CC} = 1.8 V; $V_{I(ENABLE)} \ge 0.9$ V; P_i < -40 dBm; T_{amb} = 25 °C; input matched to 50 Ω using a 6.8 nH inductor; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CC}	supply voltage	RF input AC coupled	1.5	1.8	3.1	V
I _{CC}	supply current		-	5.1	-	mΑ
Gp	power gain	no jammer	-	17	-	dB
NF	noise figure	no jammer [1]	-	0.9	-	dB
P _{i(1dB)}	input power at 1 dB	f = 1575 MHz				
	gain compression	V _{CC} = 1.8 V	-	-7	-	dBm
		V _{CC} = 2.85 V	-	-4	-	dBm
IP3 _i	input third-order intercept point	f = 1575 MHz				
		V _{CC} = 1.8 V [2]	-	5	-	dBm
		V _{CC} = 2.85 V [2]	-	7	-	dBm

^[1] PCB losses are subtracted.

2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	GND		0.0
2	V _{CC}	4 3	6 2
3	RF_OUT		5—3
4	GND_RF	5 2	Ţ ļ
5	RF_IN		1 4 aaa-006408
6	ENABLE	6 1	
		transparent top view	

3. Ordering information

Table 3. Ordering information

Type number	Package	Package			
	Name	Description	Version		
BGU6009/N2	XSON6	plastic very thin small outline package; no leads; 6 terminals; body 1.1 \times 0.9 \times 0.47 mm	SOT1230		

4. Marking

Table 4. Marking codes

Type number	Marking code
BGU6009/N2	W

^[2] $f_1 = 1713 \text{ MHz}$; $f_2 = 1851 \text{ MHz}$; $P_i = -20 \text{ dBm at } f_1$; $P_i = -65 \text{ dBm at } f_2$.

Limiting values 5.

Table 5. **Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage	RF input AC coupled		-0.5	+5.0	V
V _{I(ENABLE)}	input voltage on pin ENABLE	V _{I(ENABLE)} < V _{CC} + 0.6 V	<u>[1]</u>	-0.5	+5.0	V
$V_{I(RF_IN)}$	input voltage on pin RF_IN	DC; V _{I(RF_IN)} < V _{CC} + 0.6 V	[1][2]	-0.5	+5.0	V
V _{I(RF_OUT)}	input voltage on pin RF_OUT	DC; V _{I(RF_OUT)} < V _{CC} + 0.6 V	[1][2]	-0.5	+5.0	V
Pi	input power			-	10	dBm
P _{tot}	total power dissipation	T _{sp} ≤ 130 °C	[3]	-	55	mW
T _{stg}	storage temperature			-65	+150	°C
T _j	junction temperature			-	150	°C
V _{ESD}	electrostatic discharge voltage	Human Body Model (HBM) according to ANSI/ESDA/JEDEC standard JS-001		-	±2.5	kV
		Charged Device Model (CDM) according to JEDEC standard JESD22-C101		-	±1	kV

^[1] Warning: due to internal ESD diode protection, the applied DC voltage should not exceed V_{CC} + 0.6 V and shall not exceed 5.0 V to avoid excess current.

Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R _{th(j-sp)}	thermal resistance from junction to solder point		225	K/W

Characteristics

Table 7. Characteristics at V_{CC} = 1.8 V

f = 1559 MHz to 1610 MHz; V_{CC} = 1.8 V; $V_{I(ENABLE)} \ge 0.9$ V; P_i < -40 dBm; T_{amb} = 25 °C; input matched to 50 Ω using a 6.8 nH inductor; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CC}	supply voltage	RF input AC coupled	-	1.8	-	V
I _{CC}	supply current	$V_{I(ENABLE)} \ge 0.9 \text{ V}$	-	5.1	-	mA
		$V_{I(ENABLE)} \le 0.3 \text{ V}$	-	-	2	μΑ
Gp	power gain	no jammer	-	17	-	dB
RLin	input return loss		-	12	-	dB
RL _{out}	output return loss		-	11	-	dB
ISL	isolation		-	25	-	dB
NF	noise figure	no jammer [1]	-	0.9	-	dB
P _{i(1dB)}	input power at 1 dB gain compression	f = 1575 MHz	-	-7	-	dBm
IP3 _i	input third-order intercept point	f = 1575 MHz [2]	-	5	-	dBm

BGU6009_N2

The RF input and RF output are AC coupled through internal DC blocking capacitor.

T_{sp} is the temperature at the soldering point of GND_RF (pin 4).

Table 7. Characteristics at V_{CC} = 1.8 V ...continued

f = 1559 MHz to 1610 MHz; V_{CC} = 1.8 V; $V_{I(ENABLE)} \ge 0.9$ V; P_i < -40 dBm; T_{amb} = 25 °C; input matched to 50 Ω using a 6.8 nH inductor; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t _{on}	turn-on time	[3]	-	-	2	μS
t _{off}	turn-off time	[3]	-	-	1	μS
K	Rollett stability factor		1	-	-	-

- [1] PCB losses are subtracted.
- [2] $f_1 = 1713 \text{ MHz}$; $f_2 = 1851 \text{ MHz}$; $P_i = -20 \text{ dBm at } f_1$; $P_i = -65 \text{ dBm at } f_2$.
- [3] Within 10 % of the final gain.

Table 8. Characteristics at V_{CC} = 2.85 V

f = 1559 MHz to 1610 MHz; V_{CC} = 2.85 V; $V_{I(ENABLE)} \ge 0.9$ V; P_i < -40 dBm; T_{amb} = 25 °C; input matched to 50 Ω using a 6.8 nH inductor; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CC}	supply voltage	RF input AC coupled	-	2.85	-	V
I _{CC}	supply current	V _{I(ENABLE)} ≥ 0.9 V	-	5.5	-	mA
		$V_{I(ENABLE)} \le 0.3 \text{ V}$	-	-	2	μΑ
G _p	power gain	no jammer	-	17.5	-	dB
RLin	input return loss		-	13	-	dB
RLout	output return loss		-	11	-	dB
ISL	isolation		-	25	-	dB
NF	noise figure	no jammer [1]	-	0.95	-	dB
P _{i(1dB)}	input power at 1 dB gain compression	f = 1575 MHz	-	-4	-	dBm
IP3 _i	input third-order intercept point	f = 1575 MHz [2]	-	7	-	dBm
t _{on}	turn-on time	[3]	-	-	2	μS
t _{off}	turn-off time	[3]	-	-	1	μS
K	Rollett stability factor		1	-	-	-

- [1] PCB losses are subtracted.
- [2] $f_1 = 1713 \text{ MHz}$; $f_2 = 1851 \text{ MHz}$; $P_i = -20 \text{ dBm at } f_1$; $P_i = -65 \text{ dBm at } f_2$.
- [3] Within 10 % of the final gain.

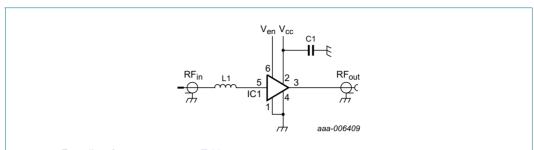
Table 9. ENABLE (pin 6)

 $-40 \, ^{\circ}\text{C} \le T_{amb} \le +85 \, ^{\circ}\text{C}; \ 1.5 \, \text{V} \le \text{V}_{CC} \le 3.1 \, \text{V}.$

V _{I(ENABLE)} (V)	State
≤ 0.3	OFF
≥ 0.9	ON

8. Application information

8.1 GNSS LNA



For a list of components, see <u>Table 10</u>.

Fig 1. Schematics GNSS LNA evaluation board

Table 10. List of components

For schematics, see Figure 1.

Component	Description	Value	Remarks
C1	decoupling capacitor	1 nF	
IC1	BGU6009/N2	-	NXP Semiconductors
L1	high-quality matching inductor	6.8 nH	Murata LQW15A

9. Package outline

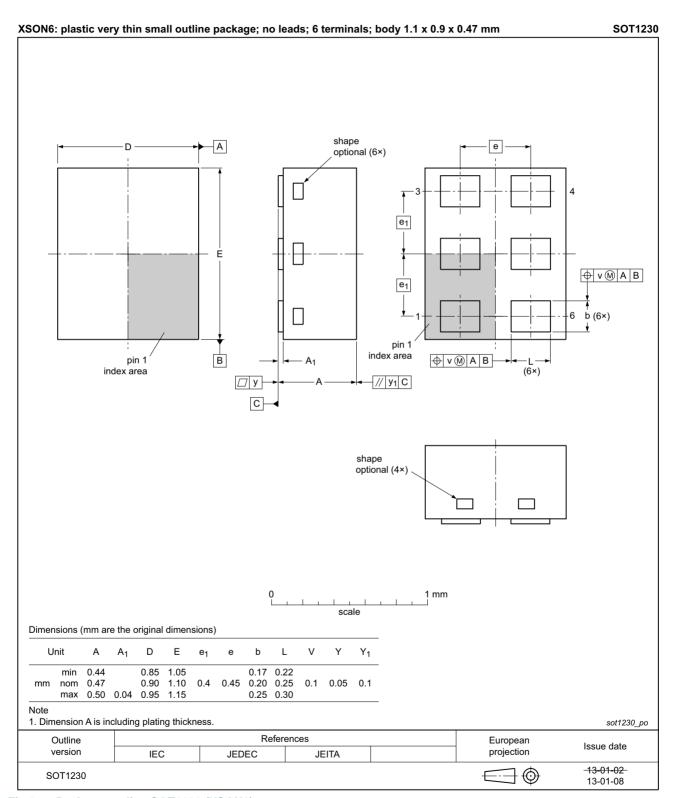


Fig 2. Package outline SOT1230 (XSON6)

10. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

11. Abbreviations

Table 11. Abbreviations

Acronym	Description
ATM	Automated Teller Machine (cash dispenser)
ESD	ElectroStatic Discharge
GLONASS	GLObal NAvigation Satellite System
GNSS	Global Navigation Satellite System
GPS	Global Positioning System
HBM	Human Body Model
LNA	Low-Noise Amplifier
MMIC	Monolithic Microwave Integrated Circuit
PCB	Printed-Circuit Board

12. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BGU6009_N2 v.4	20170118	Product data sheet	-	BGU6009_N2 v.3
Modifications:	• Section 1: adde	d GPS1002M according to our ne	w naming convention	
BGU6009_N2 v.3	20160315	Product data sheet	-	BGU6009_N2 v.2
Modifications:	Marking code F changed into W			
BGU6009_N2 v.2	20141106	Product data sheet	-	BGU6009_N2 v.1
Modifications:	Table 1 on page	2: The value of the inductor has	been corrected.	
BGU6009_N2 v.1	20141001	Product data sheet	-	-

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

13.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

13.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. NXP Semiconductors takes no responsibility for the content in this document if provided by an information source outside of NXP Semiconductors.

In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of NXP Semiconductors.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors and its suppliers accept no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk

Applications — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using NXP Semiconductors products, and NXP Semiconductors accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the NXP Semiconductors product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using NXP Semiconductors products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). NXP does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nxp.com/profile/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NXP Semiconductors hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NXP Semiconductors products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

NXP Semiconductors

BGU6009/N2

Low-noise amplifier MMIC for GPS, GLONASS, Galileo and COMPASS

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Non-automotive qualified products — Unless this data sheet expressly states that this specific NXP Semiconductors product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. NXP Semiconductors accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without NXP Semiconductors' warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond NXP Semiconductors' specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies NXP Semiconductors for any

liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond NXP Semiconductors' standard warranty and NXP Semiconductors' product specifications.

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

Translations — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

13.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

14. Contact information

For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: salesaddresses@nxp.com

NXP Semiconductors

BGU6009/N2

Low-noise amplifier MMIC for GPS, GLONASS, Galileo and COMPASS

15. Contents

1	Product profile	1
1.1	General description	1
1.2	Features and benefits	1
1.3	Applications	1
1.4	Quick reference data	2
2	Pinning information	2
3	Ordering information	2
4	Marking	2
5	Limiting values	
6	Thermal characteristics	3
7	Characteristics	3
8	Application information	5
8.1	GNSS LNA	5
9	Package outline	6
10	Handling information	7
11	Abbreviations	7
12	Revision history	7
13	Legal information	8
13.1	Data sheet status	8
13.2	Definitions	8
13.3	Disclaimers	8
13.4	Trademarks	9
14	Contact information	9
15	Contents	0

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.



Мы молодая и активно развивающаяся компания в области поставок электронных компонентов. Мы поставляем электронные компоненты отечественного и импортного производства напрямую от производителей и с крупнейших складов мира.

Благодаря сотрудничеству с мировыми поставщиками мы осуществляем комплексные и плановые поставки широчайшего спектра электронных компонентов.

Собственная эффективная логистика и склад в обеспечивает надежную поставку продукции в точно указанные сроки по всей России.

Мы осуществляем техническую поддержку нашим клиентам и предпродажную проверку качества продукции. На все поставляемые продукты мы предоставляем гарантию.

Осуществляем поставки продукции под контролем ВП МО РФ на предприятия военно-промышленного комплекса России, а также работаем в рамках 275 ФЗ с открытием отдельных счетов в уполномоченном банке. Система менеджмента качества компании соответствует требованиям ГОСТ ISO 9001.

Минимальные сроки поставки, гибкие цены, неограниченный ассортимент и индивидуальный подход к клиентам являются основой для выстраивания долгосрочного и эффективного сотрудничества с предприятиями радиоэлектронной промышленности, предприятиями ВПК и научно-исследовательскими институтами России.

С нами вы становитесь еще успешнее!

Наши контакты:

Телефон: +7 812 627 14 35

Электронная почта: sales@st-electron.ru

Адрес: 198099, Санкт-Петербург,

Промышленная ул, дом № 19, литера Н,

помещение 100-Н Офис 331